

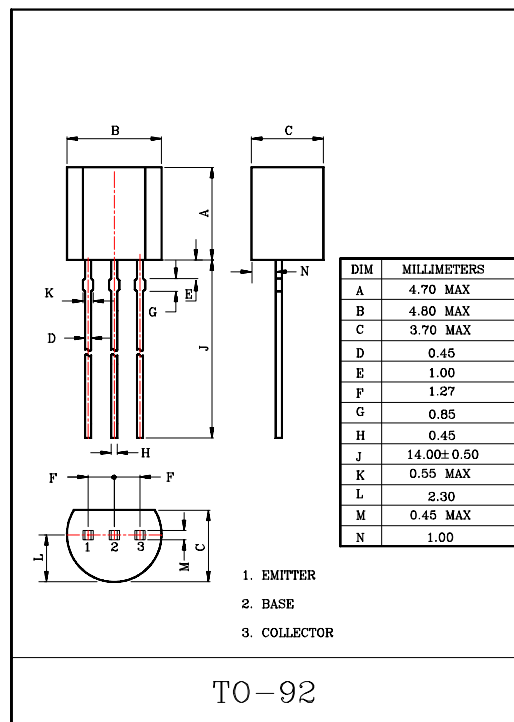
HIGH FREQUENCY APPLICATION.
HF, VHF BAND AMPLIFIER APPLICATION.

FEATURE

- High Power Gain : $G_{pe}=29dB$ (Typ.) at $f=10.7MHz$.

MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	35	V
Collector-Emitter Voltage	V_{CEO}	30	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	50	mA
Emitter Current	I_E	-50	mA
Collector Power Dissipation	P_C	625	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 ~ 150	°C

**ELECTRICAL CHARACTERISTICS (Ta=25°C)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=35V, I_E=0$	-	-	0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=4V, I_C=0$	-	-	0.1	μA
DC Current Gain	h_{FE} (Note)	$V_{CE}=5V, I_C=1mA$	40	-	198	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10mA, I_B=1mA$	-	-	0.4	V
Transition Frequency	f_T	$V_{CB}=10V, I_C=1mA, f=100MHz$	100	-	400	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=1MHz$	-	2.0	-	pF

Note : h_{FE} Classification E:40~59, F:54~80, G:72~108, H:97~146, I:132~198